

## Photomultiplier Tube with Active Divider Circuit Linear Array Multianode PMT Assembly, 8-channel(H9530 series) / 16-channel(H10515B series) / 32-channel(H7260 series)

### **FEATURES**

- High Cathode Sensitivity
   Luminous 500 μA/Im Typ. (-20 Type)
- Effective Area per Channel H9530 / H11451 / H11452 Series ... 2.0 mm × 2.5 mm × 8 Anodes H10515B / H11459 Series .... 0.8 mm × 16 mm × 16 Anodes H7260 / H11460 Series ..... 0.8 mm × 7 mm × 32 Anodes
- Good Anode Uniformity (H9530 Series)
   1:1.1 Max. (at -1000 V and peak wavelength)
- Low Cross-talk (H9530 Series)
   0.1 % Typ. (each channel)
   Black slit faceplate used
- Built In Preamplifier and High Voltage Power Supply Circuit (Module Types)



Assembly Types: H9530 Series, H10515B Series, H7260 Series

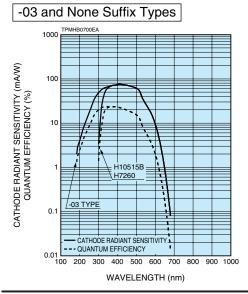


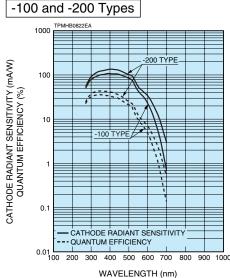
Module Types: H11451, H11452, H11459, H11460

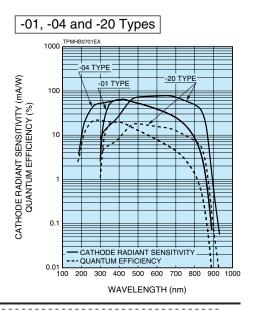
## APPLICATIONS

- Biomedical Fluorescence Detection
- Laser Scanning Detection
- Spectroscopy
- Environmental Monitoring

Figure 1: Typical Spectral Response







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## SPECIFICATIONS OF ASSEMBLY TYPES

Type No.	Anode T	Dimensional Outline	Effective Area per Channel (mm)	Channel Pitch (mm)	Dynode Structure / No. of Stages	Weight	Insulation Cover Material	
H9530 SERIES	8-channel Linear Array		See Fig.6	2.0 × 2.5	2.8	MC/12	25.5	P.O.M.
H10515B SERIES	16-channel Linear Array		See Fig.7	0.8 × 16	1	MC/10	49.0	P.O.M.
H7260 SERIES	32-channel Linear Array		See Fig.8	0.8 × 7	1	MC/10	62.0	P.O.M.

Notes: (A) MC: Metal Channel

B P.O.M.: Polyoxymethylene

Storage temperature: -15 °C to +50 °C (No condensation)

	Spectral I	Response	(F)	G		Catho	de Characte	ristics		
Type No.	Range	Peak Wavelength	Photocathode Material	Window Material	Lumi	inous	Blue Sensitivity Index (CS 5-58)	Red /White Ratio (R-68)	H Radiant	Supply Voltage
	(nm)	(nm)			Min. (μΑ/lm)	Typ. (μΑ/lm)	Typ.	`Typ.´	Typ. (mA/W)	(V dc)
H9530-01	300 to 880	420	MA	В	150	250	_	0.3	65	-1000
H9530-20	300 to 920	630	MA	В	350	500	_	0.45	78	-1000
H10515B	300 to 650	420	ВА	В	50	70	8.5	_	72	-800
H10515B-01	300 to 880	420	MA	В	150	250	_	0.3	65	-800
H10515B-03	185 to 650	420	ВА	U	50	70	8.5	_	72	-800
H10515B-04	185 to 880	420	MA	U	150	250	_	0.3	65	-800
H10515B-20	300 to 920	630	MA	В	350	500	_	0.45	78	-800
H10515B-100	300 to 650	400	SBA	В	90	105	13.5	_	110	-800
H10515B-200	300 to 650	400	UBA	В	110	135	15.5	_	130	-800
H7260	300 to 650	420	ВА	В	50	70	8.5	_	72	-800
H7260-01	300 to 880	420	MA	В	150	250	_	0.3	65	-800
H7260-03	185 to 650	420	ВА	U	50	70	8.5		72	-800
H7260-04	185 to 880	420	MA	U	150	250	_	0.3	65	-800
H7260-20	300 to 920	630	MA	В	350	500	_	0.45	78	-800
H7260-100	300 to 650	400	SBA	В	90	105	13.5	_	110	-800
H7260-200	300 to 650	400	UBA	В	110	135	15.5	_	130	-800

Notes: F BA: Bialkali MA: Multialkali SBA: Super Bialkali UBA: Ultra Bialkal

 $<sup>^{\</sup>star}$  Operating ambient temperature: 0 °C to +50 °C (No condensation)

<sup>©</sup> B: Borosilicate glass U: UV glass

H Measured at the peak wavelength



(at 25 °C)

			5 .:		(4: 25 - 5)
Socket	Maximum Supply Voltage (V dc)	Maximur  D Total Average Anode Current (μA)	Average Anode Current per Channel (µA)	Voltage Divider Current (mA)	Type No.
SD-106-T-22	-1200	80	10	0.42	H9530 SERIES
SD-108-T-22 ASP24307-02	-900	100	10	0.37	H10515B SERIES
SD-108-T-22 × 2 pcs	-900	100	6	0.37	H7260 SERIES

Notes: © Supplied

D Averaged over any interval of 30 seconds maximum.

E Measured with the maximum supply voltage.

(at 25 °C)

		Anode	Characteri	stics ①			Pulse		Unifo	ormity	
Lum	inous		per Cl	Current nannel		esponse	Linearity			en Each ode	
Min.	Тур.	Gain Typ.	(Äfter 3	Max.	Rise Time Typ.	Transit Time Spread (FWHM) Typ.	per Channel (±2 % deviation)	Cross-talk Typ.	Typ. Max.		Type No.
(A/lm)	(A/lm)	71	(nA)	(nA)	(ns)	(ns)	(mA)	(%)	71		
75	750	3 × 10 <sup>6</sup>	0.5	5	0.7	0.25	0.9	0.1	_	1: 1.1 ①	H9530-01
175	1500	3×10 <sup>6</sup>	1	10	0.7	0.25	0.9	0.1	_	1: 1.1 ①	H9530-20
50	280	4 × 10 <sup>6</sup>	0.2	2	0.6	0.18	0.8	3	1: 1.5	1: 2	H10515B
75	250	1 × 10 <sup>6</sup>	0.5	5	0.6	0.18	0.8	3	1: 1.7	1: 2.5	H10515B-01
50	280	4 × 10 <sup>6</sup>	0.2	2	0.6	0.18	0.8	3	1: 1.5	1: 2	H10515B-03
75	250	1 × 10 <sup>6</sup>	0.5	5	0.6	0.18	0.8	3	1: 1.7	1: 2.5	H10515B-04
175	500	1 × 10 <sup>6</sup>	1	10	0.6	0.18	0.8	3	1: 1.7	1: 2.5	H10515B-20
90	315	3×10 <sup>6</sup>	0.2	2	0.6	0.18	0.8	3	1: 1.5	1: 2	H10515B-100
110	405	3×10 <sup>6</sup>	0.2	2	0.6	0.18	0.8	3	1: 1.5	1: 2	H10515B-200
50	140	2 × 10 <sup>6</sup>	0.2	2	0.6	0.18	0.6	3	1: 1.5	1: 2	H7260
75	250	1 × 10 <sup>6</sup>	0.5	5	0.6	0.18	0.6	3	1: 1.7	1: 2.5	H7260-01
50	140	2 × 10 <sup>6</sup>	0.2	2	0.6	0.18	0.6	3	1: 1.5	1: 2	H7260-03
75	250	1 × 10 <sup>6</sup>	0.5	5	0.6	0.18	0.6	3	1: 1.7	1: 2.5	H7260-04
175	500	1 × 10 <sup>6</sup>	1	10	0.6	0.18	0.6	3	1: 1.7	1: 2.5	H7260-20
90	210	2 × 10 <sup>6</sup>	0.2	2	0.6	0.18	0.6	3	1: 1.5	1: 2	H7260-100
110	270	2×10 <sup>6</sup>	0.2	2	0.6	0.18	0.6	3	1: 1.5	1: 2	H7260-200

Notes: ① Anode characteristics are measured with the supply voltage. ① Uniformity is adjusted at HAMAMATSU

Figure 2: Typical Gain Characteristics

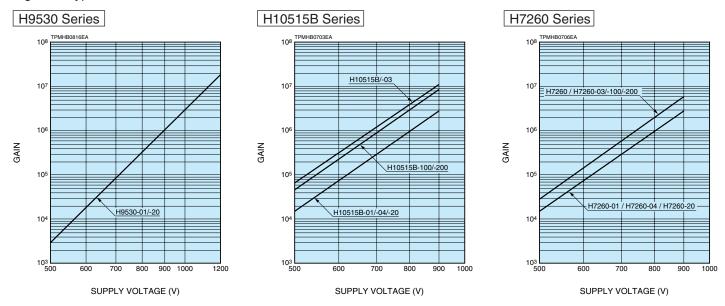
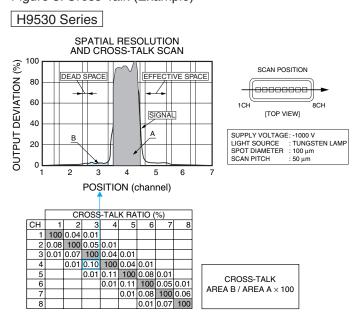
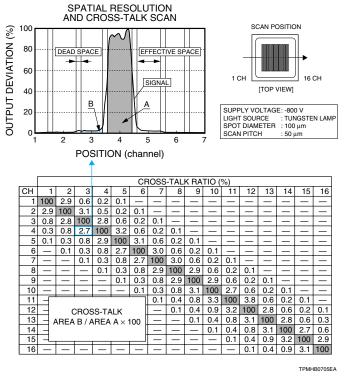


Figure 3: Cross-Talk (Example)



#### H10515B Series

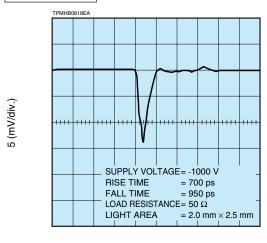


\* H7260 series is equivalent to H10515B series.



Figure 4: Typical Time Response

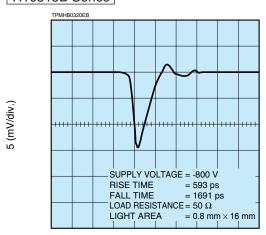




2 (ns/div.)

Light is irradiated to only one channel at this measurement.

#### H10515B Series

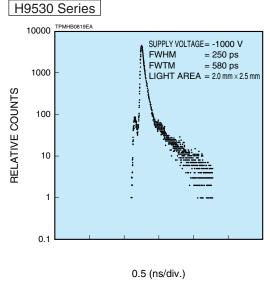


2 (ns/div.)

Light is irradiated to only one channel at this measurement.

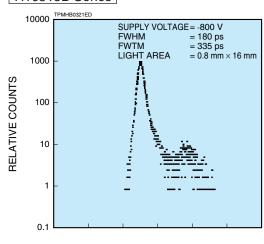
\* H7260 series is equivalent to H10515B series.

Figure 5: Typical Transit Time Spread Characteristics



Light is irradiated to only one channel at this measurement.

#### H10515B Series



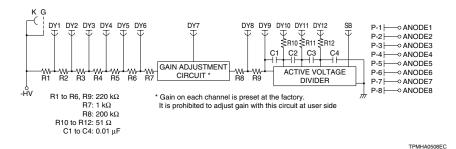
0.5 (ns/div.)

Light is irradiated to only one channel at this measurement.

\* H7260 series is equivalent to H10515B series.

Figure 6: Dimensional Outline (Unit: mm)

# MOUNTING THREADED HOLE (M2 DEPTH: 5) M2 MAX. L5 -HV INPUT TERMINAL (\$\phi 0.46) GND INPUT TERMINAL (\$\phi 0.46) ANODE #1 to #8 OUTPUT (\$\phi 0.46)



SOCKET: SD-106-T-22 (Supplied)

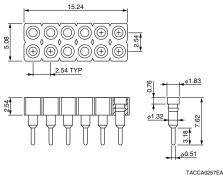
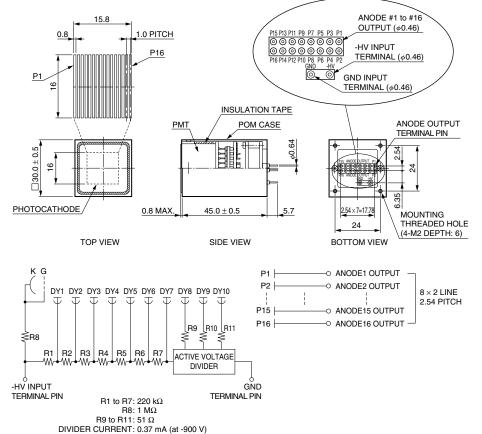
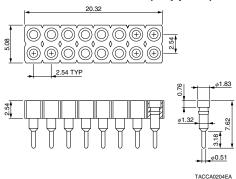


Figure 7: Dimensional Outline (Unit: mm)

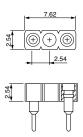
H10515B Series



#### SOCKET: SD-108-T-22 (Supplied)

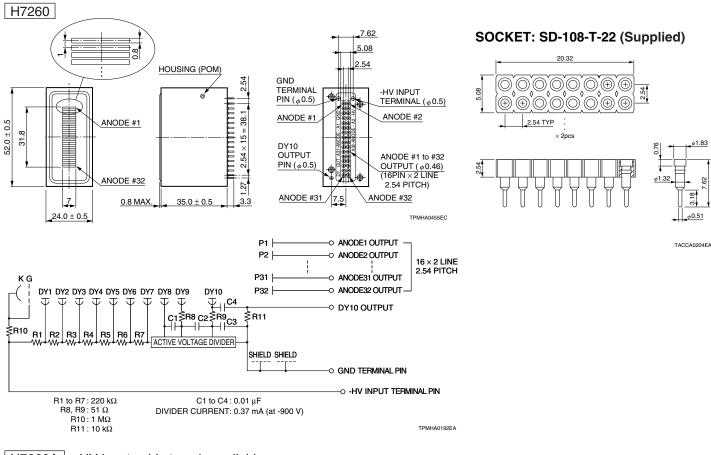


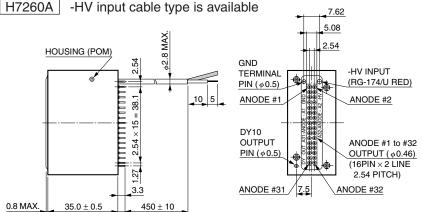
#### SOCKET: ASP24307-02 (Supplied)



TPMHA0534EB TACCA0307EA

Figure 8: Dimensional Outline and Circuit Diagram (Unit: mm)





#### RELATED PRODUCTS for H9530 / H10515B / H7260 SERIES /



#### HIGH VOLTAGE POWER SUPPLY UNIT

TPMHA0456EC

Type No.	Max. Output Voltage (V)	Output Current (mA)	Input Voltage (mA)	Dimensions (mm)	Weight (g)
C4900		0.6	+15		
C4900-01	1050	0.5	+12		0.4
C10673	-1250	0.6	+15	46 × 24 × 12	31
C10673-01		0.5	+12		

<sup>\*</sup> C10673, C10673-01: UL recognized

## SPECIFICATIONS OF MODULE TYPES

							Maximum Ratings			
Type No. Anode Type		ode Type	Dimensional Outline	Effective Area per Channel	Channel Pitch	Input Voltage	(A) Control Voltage	B DC Output	nal Voltage  BC  Pulse Output  per Channel	
				(mm)	(mm)	(V)	(V)	(V)	(V)	
H11451 SERIES	8-channel Linear Array		See Fig.10	2.0 × 2.5	2.8	±16	+4.8	+1	+10	
H11452 SERIES	8-channel Linear Array		See Fig.11	2.0 × 2.5	2.8	±16	+4.8	+1	+10	
H11459 SERIES	16-channel Linear Array		See Fig.12	0.8 × 16	1	±16	+3.6	+1	+10	
H11460 SERIES	32-channel Linear Array		See Fig.13	0.8×7	1	±16	+3.6	+0.6	+6	

Notes: (A) Input impedance = 400 k $\Omega$ 

B Load resistance = 10 k $\Omega$ 

 $\odot$  Pulse width = 10  $\mu$ s, Duty ratio = 1/100

\* Operating ambient temperature: +5 °C to +45 °C Storage temperature: -20 °C to +50 °C

	Spectral	Response	E	F		Cath	ode Characte	ristics	
Type No.	Range (nm)	Peak Wavelength (nm)	Photocathode Material	Window Material	Lum Min. (µA/lm)	Typ. (μΑ/lm)	Blue Sensitivity Index (CS 5-58) Typ.	Red /White Ratio (R-68) Typ.	G Radiant Typ. (mA/W)
H11451-01	300 to 880	420	MA	В	150	250	_	0.3	65
H11451-20	300 to 920	630	MA	В	350	500	_	0.45	78
H11452-01	300 to 880	420	MA	В	150	250	_	0.3	65
H11452-20	300 to 920	630	MA	В	350	500	_	0.45	78
H11459	300 to 650	420	ВА	В	50	70	8.5	_	72
H11459-01	300 to 880	420	MA	В	150	250	_	0.3	65
H11459-03	185 to 650	420	ВА	U	50	70	8.5	_	72
H11459-04	185 to 880	420	MA	U	150	250	_	0.3	65
H11459-20	300 to 920	630	MA	В	350	500	_	0.45	78
H11459-100	300 to 650	400	SBA	В	90	105	13.5	_	110
H11459-200	300 to 650	400	UBA	В	110	135	15.5	_	130
H11460	300 to 650	420	BA	В	50	70	8.5	_	72
H11460-01	300 to 880	420	MA	В	150	250	_	0.3	65
H11460-03	185 to 650	420	BA	U	50	70	8.5	_	72
H11460-04	185 to 880	420	MA	U	150	250	_	0.3	65
H11460-20	300 to 920	630	MA	В	350	500	_	0.45	78
H11460-100	300 to 650	400	SBA	В	90	105	13.5	_	110
H11460-200	300 to 650	400	UBA	В	110	135	15.5	_	130

Notes: © BA: Bialkali MA: Multialkali SBA: Super Bialkali UBA: Ultra Bialkal

© Measured at the peak wavelength



(at 25 °C)

Current- to-Voltage Conversion Factor (V/µA)	Frequency Bandwidth	Input Voltage (V)	Input Current Typ. (mA)	Recommended Control Voltage Adjustment Range (V)	Weight (g)	Features	Type No.
0.1	DC to 1 MHz	±11.5 to ±15.5	+26 / -18	+2.0 to +4.0	129	H9530 with preamplifier and high voltage power supply	H11451 SERIES
0.1	DC to 1 MHz	±11.5 to ±15.5	+32 / -18	+2.0 to +4.0	155	H11451 with individual gain control function	H11452 SERIES
0.1	DC to 1 MHz	±11.5 to ±15.5	+46 / -42	+2.0 to +3.2	185	H10515B with preamplifier and high voltage power supply	H11459 SERIES
0.1	DC to 1 MHz	±11.5 to ±15.5	+127 / -83	+2.0 to +3.2	246	H7260 with preamplifier, high voltage power supply and cooling fan	H11460 SERIES

Notes: D At ±15 V input voltage

(at 25 °C)

	Anode Char	acteristics (H)					Unifo	rmity	(at 25 °C)
Lumi	inous		Output ① g on PMT per Channel	Offset Voltage	Ripple Noise (peak to peak)	Cross-talk		n Each	Type No.
Min. (V/lm)	Typ. (V/lm)	Typ. (mV)	Max. (mV)	Max. (mV)	Typ. (mV)	Typ. (%)	Тур.	Max.	
$7.5 \times 10^6$	$7.5 \times 10^7$	0.05	0.5	±2	1	0.2	_	1: 1.1	H11451-01
1.75 × 10 <sup>7</sup>	1.5 × 10 <sup>8</sup>	0.1	1	±2	1	0.2	_	1: 1.1	H11451-20
7.5 × 10 <sup>6</sup>	$7.5 \times 10^{7}$	0.05	0.5	±2	1	0.2	1: 1.7	1: 2.5	H11452-01
1.75 × 10 <sup>7</sup>	1.5 × 10 <sup>8</sup>	0.1	1	±2	1	0.2	1: 1.7	1: 2.5	H11452-20
5.0 × 10 <sup>6</sup>	2.8 × 10 <sup>7</sup>	0.02	0.2	±2	1	3	1: 1.5	1: 2	H11459
7.5 × 10 <sup>6</sup>	$2.5 \times 10^{7}$	0.05	0.5	±2	1	3	1: 1.7	1: 2.5	H11459-01
5.0 × 10 <sup>6</sup>	2.8 × 10 <sup>7</sup>	0.02	0.2	±2	1	3	1: 1.5	1: 2	H11459-03
7.5 × 10 <sup>6</sup>	2.5 × 10 <sup>7</sup>	0.05	0.5	±2	1	3	1: 1.7	1: 2.5	H11459-04
1.75 × 10 <sup>7</sup>	5.0 × 10 <sup>7</sup>	0.1	1	±2	1	3	1: 1.7	1: 2.5	H11459-20
9.0 × 10 <sup>6</sup>	$3.15 \times 10^{7}$	0.02	0.2	±2	1	3	1: 1.5	1: 2	H11459-100
1.1 × 10 <sup>7</sup>	4.05 × 10 <sup>7</sup>	0.02	0.2	±2	1	3	1: 1.5	1: 2	H11459-200
5.0 × 10 <sup>6</sup>	1.4 × 10 <sup>7</sup>	0.02	0.2	±2	1	3	1: 1.5	1: 2	H11460
7.5 × 10 <sup>6</sup>	2.5 × 10 <sup>7</sup>	0.05	0.5	±2	1	3	1: 1.7	1: 2.5	H11460-01
5.0 × 10 <sup>6</sup>	1.4 × 10 <sup>7</sup>	0.02	0.2	±2	1	3	1: 1.5	1: 2	H11460-03
7.5 × 10 <sup>6</sup>	2.5 × 10 <sup>7</sup>	0.05	0.5	±2	1	3	1: 1.7	1: 2.5	H11460-04
1.75 × 10 <sup>7</sup>	5.0 × 10 <sup>7</sup>	0.1	1	±2	1	3	1: 1.7	1: 2.5	H11460-20
9.0 × 10 <sup>6</sup>	2.1 × 10 <sup>7</sup>	0.02	0.2	±2	1	3	1: 1.5	1: 2	H11460-100
1.1 × 10 <sup>7</sup>	2.7 × 10 <sup>7</sup>	0.02	0.2	±2	1	3	1: 1.5	1: 2	H11460-200

Notes: (H) Control Voltage = H11451 Series / H11452 Series: +4 V H11459 Series / H11460 Series: +3.2 V

Figure 9: Sensitivity Adjustment Method

#### H11451 / H11452 VOLTAGE PROGRAMMING RESISTANCE PROGRAMMING PMT MODULE POWER SUPPLY PMT MODULE POWER SUPPLY LOW VOLTAGE INPUT (RED) -O +11.5 V to +15.5 V LOW VOLTAGE INPUT (RED) +11.5 V to +15.5 GND (BLACK) GND (BLACK) -O GND -O GND LOW VOLTAGE INPUT (GREEN) LOW VOLTAGE INPUT (GREEN) Vcont INPUT (WHITE) O-11.5 V to -15.5 \ O -11.5 V to -15.5 \ Vcont INPUT (WHITE) Vref OUTPUT (BLUE) Vref OUTPUT (BLUE) 1: When using a potentiometer to GND (BLACK) GND (BLACK) adjust sensitivity, monitor the SIGNAL OUTPUT SIGNAL OUTPUT control voltage so that it does SOCKET: EHF-108-01-F-D-RA SOCKET: EHF-108-01-F-D-RA not exceed +4.8 V. 0+2.0 V to +4.0 V · Adjust the control voltage to adjust MONITOR C POTENTIOMETER \*1 the sensitivity. OGND (100 kΩ Max.) Electrically insulate the reference TPMHC0241EA voltage output. H11459 / H11460 VOLTAGE PROGRAMMING RESISTANCE PROGRAMMING PMT MODULE POWER SUPPLY PMT MODULE POWER SUPPLY LOW VOLTAGE INPUT (RED) LOW VOLTAGE INPUT (RED) ← +11.5 V to +15.5 V -O +11.5 V to +15.5 V GND (BLACK) GND (BLACK) OGND -O GND LOW VOLTAGE INPUT (GREEN) LOW VOLTAGE INPUT (GREEN) -O -11.5 V to -15.5 \ O -11.5 V to -15.5 V Vcont INPUT (WHITE) Vref OUTPUT (BLUE) Vcont INPUT (WHITE) Vref OUTPUT (BLUE) \*1: When using a potentiometer to GND (BLACK) GND (BLACK) adjust sensitivity, monitor the control voltage so that it does SIGNAL OUTPUT SIGNAL OUTPUT not exceed +3.6 V. SOCKET: EHF-117-01-F-D-RA (samtec) SOCKET: EHF-117-01-F-D-RA \_+2.0 V to +3.2 V · Adjust the control voltage to adjust MONITOR O POTENTIOMETER\*1 the sensitivity. OGND (100 kΩ Max.) · Electrically insulate the reference voltage output. TPMHC0242EA

Figure 10: Dimensional Outline (Unit: mm)

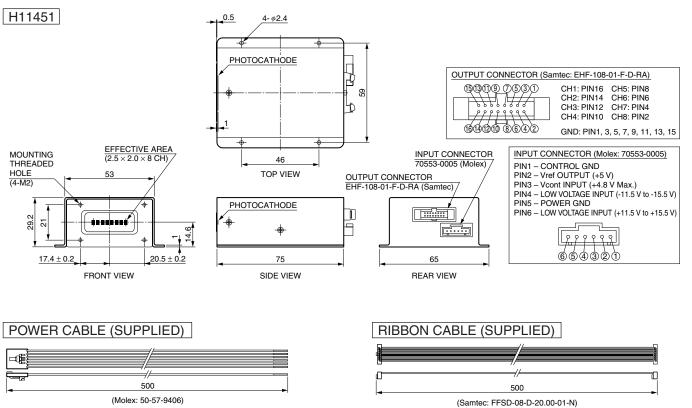


Figure 11: Dimensional Outline (Unit: mm)

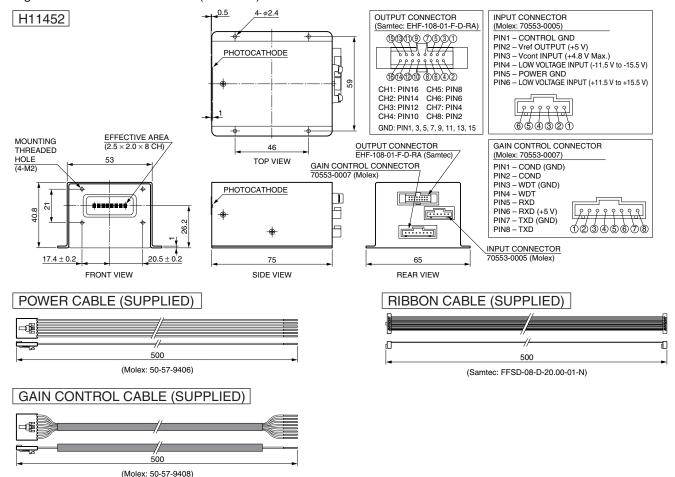
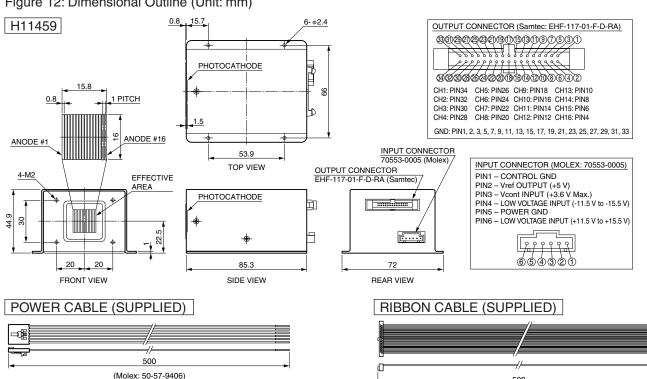
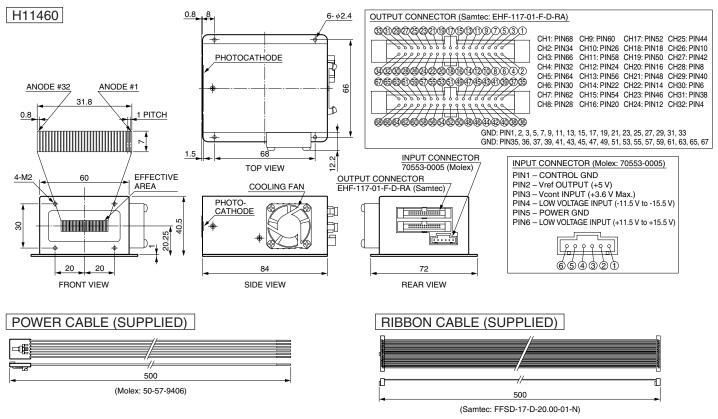


Figure 12: Dimensional Outline (Unit: mm)

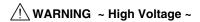


500 (Samtec: FFSD-17-D-20.00-01-N) TPMHA0568EA

Figure 13: Dimensional Outline (Unit: mm)



TPMHA0570EA



The product is operated at high voltage potential. Further, the metal housing of the product is connected to the photocathode (potential) so that it becomes a high voltage potential when the product is operated at a negative high voltage (anode grounded). Accordingly, extreme safety care must be taken for the electrical shock hazard to the operator or the damage to the other instruments.

\* PATENT: USA Pat. No. 5410211 PATENT PENDING: JAPAN 12, USA 8, EUROPE 9

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